SOLITON-IMPURITY INTERACTIONS IN THE PEIERLS MODEL

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The interaction of amplitude soliton with an impurity in a one dimensional Peierls system is investigated. The total energy is calculated. It is shown that bond soliton-impurity states may be formed. The soliton reflection coefficient and the transition frequencies between the bound states are estimated.

The conductivity properties of most quasionedimensional Charge Density Waves (CDW) systems are varied in wide limits by doping. It is known that due to the selftrapping of the doped electron or the hole amplitude solitons are formed. Up to date the problem of soliton-impurity interaction (the interaction of soliton with the dopand ion in the case of doping) has not solved finally. The dynamic of CDW is consiedered usually in the frameworks of the phase CDW Hamiltonian [1-3]. Therefore only phase solitons can be taken into account. In this work we study the interaction of the amplitude soliton with the impurity, localized near the chain. We suppose that the interaction potential width is much smaller than the soliton size, therefore we consiedere a local interaction.

The Hamiltonian of the 1d Peierls model is

$$H_0 = \int dx \Psi^{\dagger} \left[-iv_F \frac{\partial}{\partial x} \sigma_x + \Delta(x) \sigma_+ + \Delta(x)^* \sigma_- \right] \Psi + \frac{\Delta^2}{g^2}, \tag{1}$$

where $\Psi^{\dagger}(x) = (\Psi^{\dagger}_{+}(x), \Psi^{\dagger}_{-}(x))$ are components of electron operators with momenta near right and left Fermi points, v_F is the Fermi velocity; $\sigma_z, \sigma_{\pm} = \sigma_x \pm i\sigma_y$ are Pauli matrixes, g is the electron-phonon interaction constant.

The interaction Hamiltonian has the form

$$H_{int}(x) = \Psi^{\dagger}(x)V_1(x)\Psi(x) + \Psi^{\dagger}(x)V_2(x)\sigma_+\Psi(x) + \Psi^{\dagger}(x)V_2^*(x)\sigma_-\Psi(x). \tag{2}$$

The first term in (2) describes the forward scattering, the second is due to the backscattering. We will suppose that the interaction is localized on distances more less than the soliton width ξ_0 , therefore

$$V_1(x) = V_1\delta(x-x_i), \quad V_2(x) = V_2\delta(x-x_i),$$

where x_i is the impurity position, and $V_2 = |V_2| e^{i\beta}$. For the sake of simplicity we omit spin indexes and consider the spin diagonal scattering only. By introducing the Green function of the nonperturbated Schrodinger equation

$$(i\partial/\partial t + iv_F \sigma_z \partial/\partial x - \Delta(x)\sigma_+ - \Delta(x)^* \sigma_-)G(x, x', t - t') =$$

$$= \delta(x - x')\delta(t - t')$$
(3)

it is easily to obtain in mixed representation (x,ω)

$$G(x, x', \omega) = \sum_{\lambda} \frac{\varphi_{\lambda}(x) \otimes \varphi_{\lambda}^{\dagger}(x')}{\omega - \epsilon_{\lambda} + i\delta}$$

where $\{\varphi_{\lambda}(x)\} = \{\varphi_{+,\lambda}(x), \varphi_{-,\lambda}\}$ is the complete set of nonperturbated Hamiltonian eigenfunctions for a given function $\Delta(x)$.

From (1) - (3) we have that eigenfunctions of the Hamiltonian $H = H_0 + H_{int}$ are determinated from the following equation:

$$\Psi(x,E) = \int dy G(x,y,E) H_{int}(y) \Psi(y,E) = G(x,x_i,E) \hat{V} \Psi(x_i,E), \tag{4}$$

where

$$\hat{V} = \left(\begin{array}{cc} V_1 & V_2 \\ V_2^* & V_1 \end{array} \right).$$

The eigenvalues E are determined from (4):

$$\det(G(x_i, x_i, E)\hat{V} - 1) = 0$$

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$$(|V_2|^2 - V_1^2)\det G + V_2^*G_{12} + V_2G_{21} + V_1\operatorname{tr} G - 1 = 0.$$
 (5)

Let us assume that in the absence of an impurity there is one amplitude soliton in the chain. In this case we take as a nonperturbed set of wavefunctions $\{\varphi_{\lambda}(x)\}$ the one soliton solution [4]:

$$\varphi_{+,\epsilon} = \frac{\Delta_1 + \epsilon + v_F p + i\Delta_2 \tanh[\Delta_2(x - x_s)/v_F]}{\sqrt{2L\epsilon(\epsilon + \Delta_1)}} \exp(ipx)$$

$$\varphi_{-,\epsilon} = \frac{\Delta_1 + \epsilon - v_F p - i\Delta_2 \tanh[\Delta_2(x - x_s)/v_F]}{\sqrt{2L\epsilon(\epsilon + \Delta_1)}} \exp(ipx)$$
(6)

for a continuum spectrum with the dispersion $\epsilon^2 = v_F^2 p^2 + \Delta^2$, $\Delta^2 = \Delta_1^2 + \Delta_2^2$, L is the chain length, and

$$\varphi_{+} = -\varphi_{-} = \frac{\sqrt{\Delta_{2}}}{2\cosh[\Delta_{2}(x - x_{s})/v_{F}]}, \quad \epsilon = -\Delta_{1}$$
 (7)

for the local level. The deformation $\Delta(x) = \Delta_1 + i\Delta_2 \tanh[\Delta_2(x-x_s)/v_F]$ consists of the constant term due to the polimer structure and the Peierls deformation $\Delta_2(x)$ (x_s is the soliton position).

After substituting (6), (7) to (5) we have the following equation for the shifts of valent band levels $\delta \epsilon = E - \epsilon(p)$:

$$0 = (\delta \epsilon L)^{2} - (\delta \epsilon L) \{ V_{1} (2 - \frac{\Delta^{2} \cosh^{-2}(z)}{\epsilon (\epsilon + \Delta_{1})}) + |V_{2}| \cos \beta (\frac{2\Delta_{1}}{\epsilon} + \frac{\Delta_{2}^{2} \cosh^{-2}(z)}{\epsilon (\epsilon + \Delta_{1})}) + |V_{2}| \sin \beta \frac{2\Delta_{2} \tanh(z)}{\epsilon} \} + (V_{1}^{2} - |V_{2}|^{2}) (\frac{\epsilon^{2} - \Delta^{2}}{4\epsilon^{2}}),$$
(8)

where $z = (x_i - x_s)\Delta_2/v_F$. We obtain from (8) that

$$\delta\epsilon(p)L + \delta\epsilon(-p)L = V_1(2 - \frac{\Delta^2\cosh^{-2}(z)}{\epsilon(\epsilon + \Delta_1)}) +$$

$$+ \mid V_2 \mid \cos \beta \left(\frac{2\Delta_1}{\epsilon} + \frac{\Delta_2^2 \cosh^{-2}(z)}{\epsilon(\epsilon + \Delta_1)}\right) + \mid V_2 \mid \sin \beta \left(\frac{2\Delta_2 \tanh(z)}{\epsilon}\right). \tag{9}$$

For the local level E_0 shift we have by the similar way that

$$\delta \epsilon_0 = E_0 + \Delta_1 = -(V_1 + |V_2| \cos \beta) \frac{\Delta_0}{2v_F \cosh^2(z)}. \tag{10}$$

The total energy shift $\delta W = W - W_0$ is found from (9), (10)

$$\delta W(x_s - x_i) = \sum_{\text{cont}} \delta \epsilon + \delta \epsilon_0 =$$

$$= (V_1 + |V_2| \cos \beta) \frac{\Delta_2}{2v_F \cosh^2(z)} (\nu_0 - 2\frac{\theta}{\pi}) -$$

$$- |V_2| \sin \beta \frac{2\Delta_2}{\sigma^2} \tanh(z), \tag{11}$$

where ν_0 is the filling factor of the local level ($\nu_0 = 0, 1, 2$), $\theta = \tan^{-1}(\Delta_2/\Delta_1)$. For the pure Peierls model ($\Delta_1 = 0$, $\theta = \pi/2$) we have from (11) that

$$\delta W(x_s - x_i) = (V_1 + |V_2| \cos \beta) \frac{\Delta_2}{2v_F \cosh^2(z)} (\nu_0 - 1) - |V_2| \sin \beta \frac{2\Delta_2}{a^2} \tanh(z).$$
(12)

In the case

$$(V_1 + |V_2|\cos\beta)(\nu_0 - 1) < -|V_2|\sin\beta|4v_F/g^2$$
(13)

we have the bond state of the soliton and the impurity. In other cases the energy minimum is achieved at $z \to \infty$ or $z \to -\infty$

When obtaining the expression (9), (10), we have supposed that the energy level shift is much smaller than the distance between the neighbour levels of the quasicontinuous spectrum. It is right if V_1/v_F , $|V_2|/v_F \ll 1$ for all levels in the valence band except a small vicinity of the valence band edge. But the contribution of this vicinity to the total energy (11) is small by the additional factor of order of Δ/ϵ_F .

Now we estimate the transition frequencis between the soliton bound levels and the soliton reflection coefficient on the impurity potential. We consider the soliton as the quantum particle, which is discribed by the Hamiltonian [5]:

$$H_s = -\frac{1}{2M_s} \frac{\partial^2}{\partial x_s^2} + \delta W(x_s - x_i), \tag{14}$$

where M_s is the soliton effective mass, x_s is the solitone coordinate and $\delta W(x_s - x_i)$ is given by (12). In order to facilitate the problem we consider the forward

scattering only (i.e. put $V_2 = 0$) and suppose that $V_1(\nu_0 - 1) < 0$. Then we obtain for the energy levels:

$$E_n = -\frac{1}{8M_s \xi_0^2} (\sqrt{1 + 8M_s \mid U_0 \mid \xi_0^2} - 1 - 2n)^2$$

and for the reflection coefficient

$$R = \frac{\cos^2(\pi/2\sqrt{1 + 8M_s \mid U_0 \mid \xi_0^2})}{\sinh^2(\pi\xi_0 k) + \cos^2(\pi/2\sqrt{1 + 8M_s \mid U_0 \mid \xi_0^2})}$$

where

$$|U_0| = |\Delta_2 V_1(\nu_0 - 1)/2|, \xi_0 = v_F/\Delta_2,$$

n is the integer, $0 \le n < (\sqrt{1+8M_s \mid U_0 \mid \xi_0^2} - 1)/2$ and k is the wavevector of the soliton. For the effective mass of the soliton we have from [4] that

$$M_s = \frac{4\Delta_2^2}{\xi_0 \omega_0^2 q^2},$$

where ω_0 is the phonon frequency with momentum near $2p_E$.

Taking into account the data for the polyacetylene [5]: $\Delta_2 \simeq 0.7 \,\mathrm{eV}$, $v_F \simeq 6 \,\mathrm{eV} \mathring{A}$, $\omega_0^2 \simeq 6 \cdot 10^{28} \,\mathrm{sec}^{-2}$, $g^2 \simeq 8 \,\mathrm{eV} \mathring{A}$ and $V_1 \sim 1 \,\mathrm{eV} A$ we find that $M_s \simeq 9 m_0$ (m_0 is electron mass) and frequencies:

$$\omega_{nm} = E_n - E_m \sim 10^2 - 10^3 \text{cm}^{-1}$$
.

For the reflection coefficient we obtain:

$$R \sim 10^{-6}$$
. (15)

The coefficient R has been calculated for the thermal wavevector at $T = 300 \,\mathrm{K}$. From (15) we see that the solitons can put very essential contribution into the conductivity of the system, and the transitions between bound states of the soliton can put a contribution into the infrared absorbtion coefficient.

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